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Sulfur doped Co/SiO₂ catalysts for chirally selective synthesis of single walled carbon nanotubes†

Hong Wang, Kunli Goh, Rui Xue, Dingshan Yu, Wenchao Jiang, Raymond Lau and Yuan Chen*

Monochiral single-walled carbon nanotubes have many potential uses, especially in the field of electronics and medical applications. Here we demonstrate a method to activate three types of Co/SiO₂ catalysts via sulfur-doping for the synthesis of tubes with a narrow chiral distribution around (9,8) chirality.

Electronic and optical properties of single-walled carbon nanotubes (SWCNTs) are correlated with their geometric structures, i.e. chirality index \((n,m)\). Thus, many potential applications require the use of monochiral SWCNTs. Chirally selective synthesis of nanotubess is the ultimate goal in SWCNT production, which remains a great challenge. In common growth methods, i.e. chemical vapor deposition (CVD), carbon precursors decompose at high temperature to form atomic carbon species, which then nucleate into one-dimensional tubes on catalytic particles. Theoretical studies suggest that catalysts play a critical role in the \((n,m)\) selectivity. To control SWCNT \((n,m)\) structures, the size of catalytic particles need to be first confined in a suitable range. However, metal species are mobile and form particles of various sizes at high growth temperatures, which eventually results in the growth of multiwalled carbon nanotubes (MWCNTs), graphite and amorphous carbon.

Co catalysts supported on silica substrates (Co/SiO₂) are the most often used catalysts for \((n,m)\) selective growth of SWCNTs. Several approaches have been used to control the nucleation of Co, e.g. stabilizing Co clusters in bimetallic alloys, incorporating Co ions into mesoporous substrates, forming dispersed surface Co silicates, anchoring reduced Co atoms by unreduced Co ions, and creating strong interfacial Co–Si interactions. Most of these approaches only result in the selective growth of small-diameter (6,5) tubes. Some previous studies had shown that when sulfur (S) species are added to carbon precursors, it can promote the growth rate and yield of the nanotubes, and change MWCNT diameters. However, to the best of our knowledge, no work has been reported on the direct doping of S in solid catalysts to control metal particles for SWCNT growth.

In this work, we have demonstrated that non-selective Co/SiO₂ catalysts can be converted into efficient chiral selective catalysts by S doping. SWCNTs were characterized by photoluminescence (PL), UV-vis-near-infrared (UV-vis-NIR) absorption and Raman spectroscopies. Catalysts were characterized by elemental analysis, H₂ temperature programmed reduction (H₂-TPR), and UV-vis diffuse reflectance spectroscopy. The molecular structural changes of Co species on SiO₂ caused by S doping are believed to be responsible for the chiral selectivity.

Three Co/SiO₂ catalysts with 1 wt% Co were prepared by the impregnation method using Co precursors, including Co(n) acetylacetone (Co(acac)n, Sigma-Aldrich, 97%), Co(n) chloride (CoCl₂, Alfa Aesar, 97%), and Co(n) nitrate hexahydrate (Co(NO₃)₂·6H₂O, Sigma-Aldrich, 99.999%). They are denoted as CoACAC/SiO₂, CoCl/SiO₂, and CoN/SiO₂, respectively. To add S, the calcined Co/SiO₂ catalysts were impregnated by dilute sulfuric acid (H₂SO₄, 0.04 mol L⁻¹) at 8 mL solution per g catalyst ratio for 1 h. The resulting S doped catalysts were marked as CoACAC/SiO₂/S, CoCl/SiO₂/S, and CoN/SiO₂/S, respectively (see ESI† for details). Catalysts were introduced into a CVD reactor, and first reduced under pure H₂ (1 bar, 50 sccm) from room temperature to 540 °C at 20 °C min⁻¹, and then further heated to 780 °C under an Ar flow (1 bar, 50 sccm). At 780 °C, pressurized CO (6 bar, 200 sccm) replaced Ar, and the SWCNT growth lasted for 1 h. As-synthesized SWCNTs with catalysts were first characterized by Raman spectroscopy, and then dissolved in NaOH aqueous solution (1.5 mol L⁻¹) to remove SiO₂. The carbon deposits were then dispersed in 2 wt% sodium dodecyl benzene sulfate (SDBS, Aldrich) D₂O solution. The SWCNT suspension obtained after centrifugation at 50 000 g was characterized by PL and UV-vis-NIR absorption spectroscopies (see ESI† for details).

PL maps in Fig. 1a–f show that two undoped Co/SiO₂ catalysts (CoACAC/SiO₂ and CoCl/SiO₂) resulted in small-diameter tubes (<0.9 nm), such as [6,5], [7,5], [7,6] and [8,4]. CoN/SiO₂ is not active for SWCNT growth. This is in agreement with previous studies using various SiO₂ supported Co catalysts. In contrast, after doping with S, the major \((n,m)\) products are large-diameter tubes (>1.1 nm), such as [9,8], [9,7], [10,6], and [10,9]. The abundance of these

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have demonstrated that S doping can shift the (n,m) selectivity of SWCNTs grown on undoped and S doped Co/SiO2 catalysts. PL maps: (a) CoACAC/SiO2, (b) CoCl/SiO2, (c) CoN/SiO2, (d) CoACAC/SiO2/S, (e) CoCl/SiO2/S, and (f) CoN/SiO2/S. Some major (n,m) species identified on PL maps are marked. Absorption spectra: undoped (g) and S doped (h). The shaded pink indicates the E11 absorption band and the shaded blue shows the overlapping E22 and E21 bands.

The S content in CoACAC/SiO2/S, CoCl/SiO2/S, and CoN/SiO2/S was found to be 0.91, 1.17 and 0.83 wt%, respectively. This confirms the existence of S. Next, H2-TPR was employed to study the reducibility of Co species. Fig. 2 shows that CoACAC/SiO2 displays a peak around 797 °C, which is due to the surface Co hydrosilicate.17 CoCl/SiO2 has multiple peaks at 360–800 °C, which may come from the reduction of CoO, CoCl2, and surface Co silicate. CoN/SiO2 possesses a broad peak around 290 °C which can be attributed to Co3O4 and CoO. In contrast, all the TPR profiles of the three S doped Co/SiO2 catalysts have a sharp peak at 493–506 °C, similar to our recently reported chiral selective Co/SiO2 catalyst.18 In addition, it is observed that the Co2+ peaks of undoped catalysts become significantly smaller after S doping, and new peaks around 800 °C appear on CoCl/SiO2/S and CoN/SiO2/S. This observation suggests the formation Co hydrosilicate or surface Co silicate,28 while the 797 °C peak of CoACAC/SiO2 becomes smaller. Lastly, UV-vis diffuse reflectance spectroscopy was used to probe the surface chemistry of the catalysts. As shown in Fig. S2 in the ESI,† CoACAC/SiO2 has two peaks around 570 and 650 nm, suggesting the formation of surface Co silicates.28 The spectrum of CoCl/SiO2 shows two broad peaks at 550 and 720 nm, indicating the presence of CoO2 and CoCl2. The spectrum of CoN/SiO2 is similar to that of Co3O4, having two broad peaks at ~400 and 720 nm, which can be assigned to the transitions of octahedral configured Co3+ ions.29 In contrast, all the three S doped Co/SiO2 catalysts have a broad peak around 535 nm, similar to that of CoSO4, and this suggests the existence of Co species bonded to SO42–.

Doping sulfate ions into metal oxides has created various solid acid catalysts, such as SO42–/ZrO2, SO42–/TiO2, and SO42–/Fe2O3.30,31 Based on our characterization of the Co/SiO2 catalysts, we propose the following mechanism to explain their (n,m) selectivity in SWCNT growth. As shown in Fig. 3, undoped Co/SiO2 catalysts contain CoO3, Co hydrosilicate, and surface Co silicates, which are evident from their H2-TPR profiles and UV-vis spectra. Surface Co silicates on CoACAC/SiO2 and CoCl/SiO2 would be reduced and nucleated into small Co nanoparticles,

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which are selective toward small-diameter SWCNTs. Similarly, we propose that the co-existence of S atoms near Co atoms may limit the nucleation of Co and/or form Co-S compounds, which changes the selectivity of the catalysts to favor the formation of (9,8). As discussed in our previous study, the selectivity toward (9,8) may be attributed to the close match between carbon caps and the most stable Co particles in their size range, as well as the higher growth rate of high chiral angle tubes. As active Co nanoparticles are embedded under or near SiO2 surface, we are still unable to quantify their size and composition in transmission electron microscopy analysis (see Fig. S3 in the ESI†). Furthermore, we propose a reaction between H+ ions and CoOx releasing Co ions to form well dispersed Co hydroxysilicate and surface Co silicate on SiO2, which would increase the selectivity toward SWCNTs. This is suggested by the increased SWCNT selectivity of CoN/SiO2/S. To further verify the proposed mechanism, we doped CoN/SiO2 using (NH4)2SiO4. We expected the same effect from SO4^{2-}, but selectivity toward SWCNTs may be compromised since NH4+ is less reactive than H+. As shown in Fig. S4–S7 in the ESI†, (NH4)2SO4 doped CoN/SiO2 can result in the growth of (9,8) nanotubes because of Si doping. However, it is less selective to SWCNTs as compared to CoN/SiO2/S. This provides strong credibility to our proposed mechanism.

In conclusion, we have demonstrated a method to convert three types of Co/SiO2 catalysts, which are either inactive for the SWCNT growth or only selective to small-diameter nanotubes, into chirally selective catalysts to grow SWCNTs enriched with large-diameter (9,8) tubes (up to 40.5%) by doping catalysts with S. We also proposed in the mechanism that S atoms near Co atoms assist the formation of Co nanoparticles which are selective to (9,8) tubes. Moreover, H+ ions may react with CoOx to form well dispersed Co hydroxysilicate and surface Co silicate on SiO2, which increases the selectivity to SWCNTs.

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Notes and references